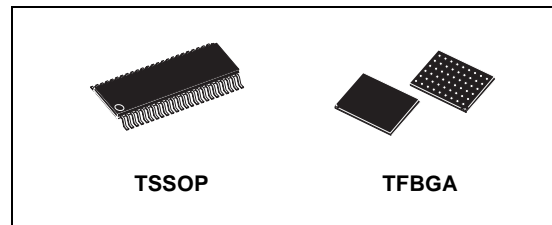




# 74VCX16245

## LOW VOLTAGE CMOS 16-BIT BUS TRANSCEIVER (3-STATE) WITH 3.6V TOLERANT INPUTS AND OUTPUTS

- 3.6V TOLERANT INPUTS AND OUTPUTS
- HIGH SPEED:
  - $t_{PD} = 2.5 \text{ ns (MAX.) at } V_{CC} = 3.0 \text{ to } 3.6\text{V}$
  - $t_{PD} = 3.2 \text{ ns (MAX.) at } V_{CC} = 2.3 \text{ to } 2.7\text{V}$
  - $t_{PD} = 5.7 \text{ ns (MAX.) at } V_{CC} = 1.8\text{V}$
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
  - $|I_{OH}| = I_{OL} = 24\text{mA (MIN) at } V_{CC} = 3.0\text{V}$
  - $|I_{OH}| = I_{OL} = 18\text{mA (MIN) at } V_{CC} = 2.3\text{V}$
  - $|I_{OH}| = I_{OL} = 6\text{mA (MIN) at } V_{CC} = 1.8\text{V}$
- OPERATING VOLTAGE RANGE:
  - $V_{CC(OPR)} = 1.8\text{V to } 3.6\text{V}$
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 16240
- LATCH-UP PERFORMANCE EXCEEDS 300mA (JESD 17)
- ESD PERFORMANCE:
  - HBM > 2000V (MIL STD 883 method 3015);
  - MM > 200V



### ORDER CODES

PACKAGE	TUBE	T & P
TSSOP		74VCX16245TTR
TFBGA		74VCX16245LBR

### DESCRIPTION

The 74VCX16245 is a low voltage CMOS 16 BIT BUS TRANSCEIVER (3-STATE) fabricated with sub-micron silicon gate and five-layer metal wiring C<sup>2</sup>MOS technology. It is ideal for low power and very high speed 1.8 to 3.6V applications; it can be interfaced to 3.6V signal environment for both inputs and outputs.

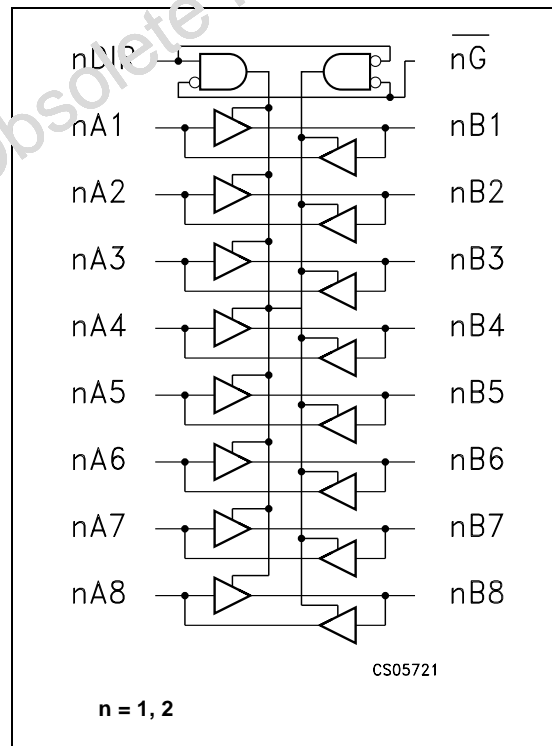
This IC is intended for two-way asynchronous communication between data buses; the direction of data transmission is determined by DIR input.

The two enable inputs nG can be used to disable the device so that the buses are effectively isolated.

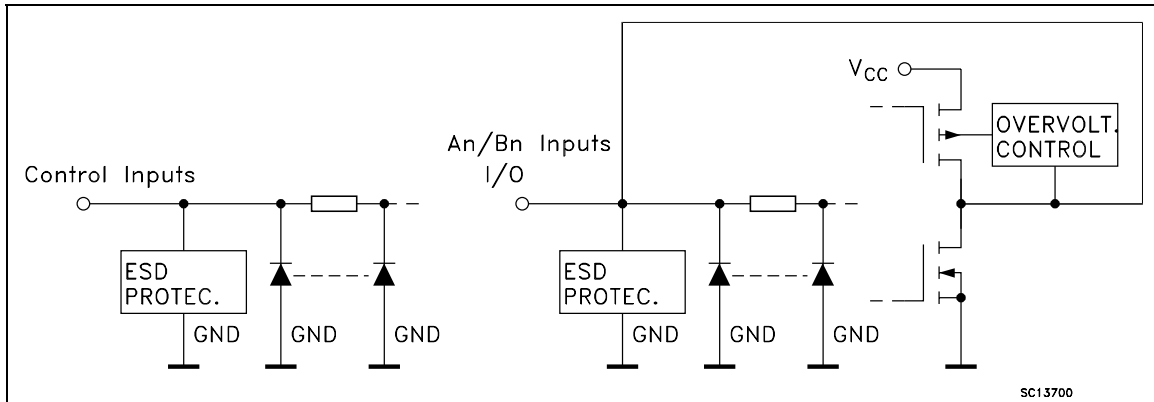
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

All floating bus terminals during High Z State must be held HIGH or LOW.

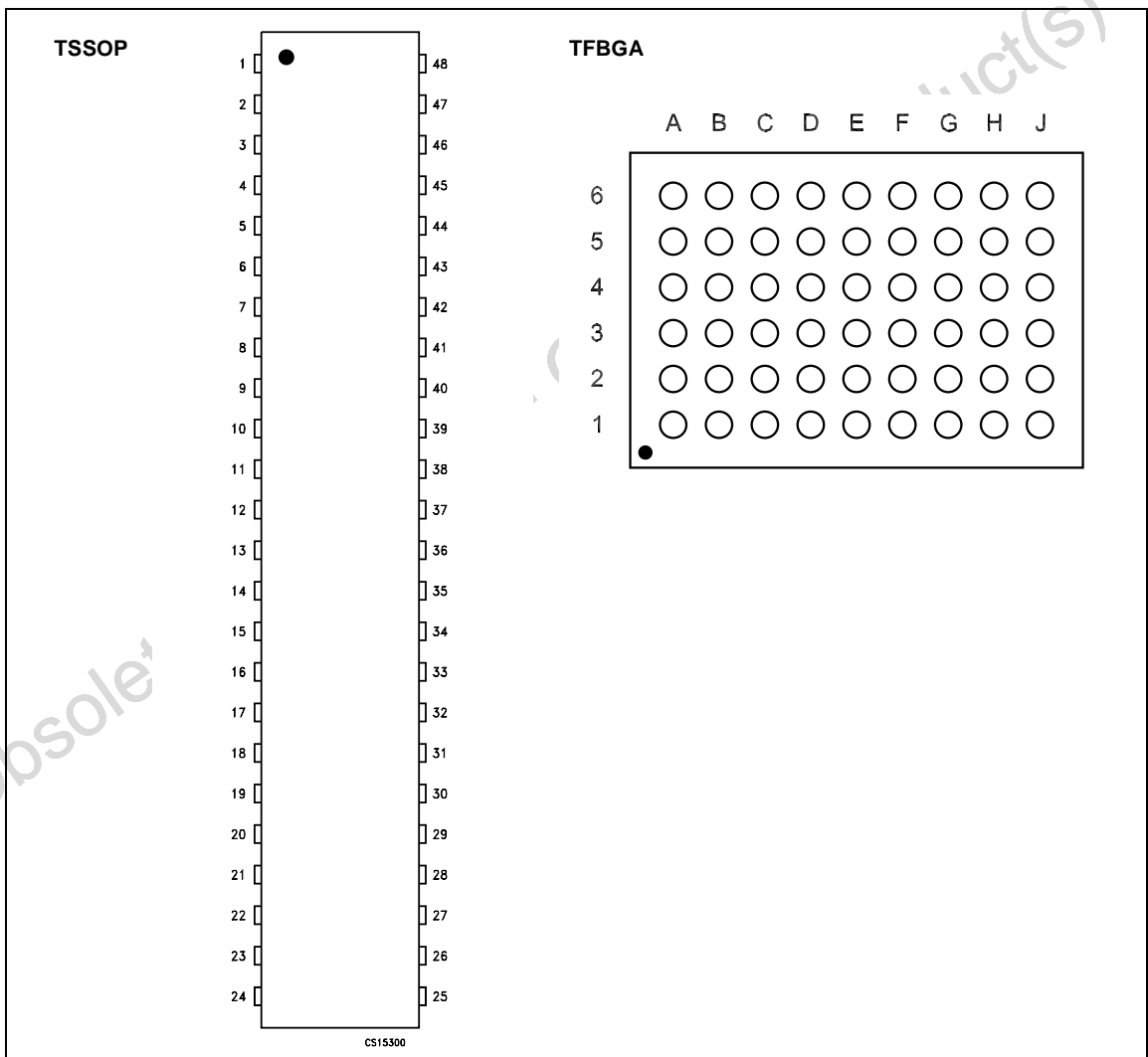
### PIN CONNECTION



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN CONNECTION (top view for TSSOP, top through view for BGA)



## PIN DESCRIPTION

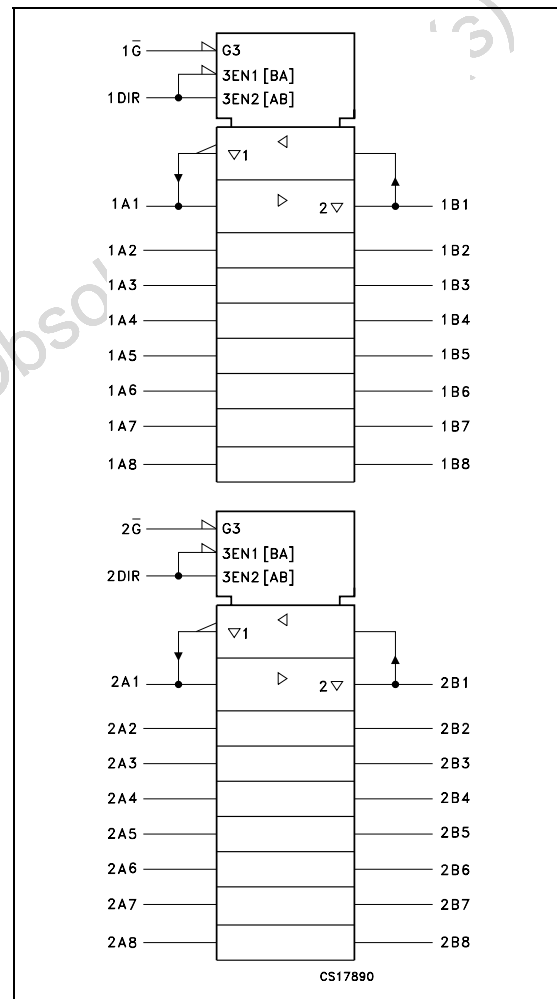
PIN N° FOR TSSOP	PIN N° FOR TFBGA	SYMBOL	NAME AND FUNCTION
1	A3	1DIR	Directional Control
2, 3, 5, 6, 8, 9, 11, 12	A1, B2, B1, C2, C1, D2, D1, E2	1B1 to 1B8	Data Inputs/Outputs
13, 14, 16, 17, 19, 20, 22, 23	E1, F2, F1, G2, G1, H2, H1, J1	2B1 to 2B8	Data Inputs/Outputs
24	J3	2DIR	Directional Control
25	J4	2G	Output Enable Input
36, 35, 33, 32, 30, 29, 27, 26	E6, F5, F6, G5, G6, H5, H6, J6	2A1 to 2A8	Data Inputs/Outputs
47, 46, 44, 43, 41, 40, 38, 38	A6, B5, B6, C5, C6, D5, D6, E5	1A1 to 1A8	Data Inputs/Outputs
48	A4	1G	Output Enable Input
4, 10, 15, 21, 28, 34, 39, 45	D3, D4, E3, E4, F3, F4	GND	Ground (0V)
7, 18, 31, 42	C3, G3, C4, G4	V <sub>CC</sub>	Positive Supply Voltage
	A2, A5, B3, B4, H3, H4, J2, J5	N.C.	No Connect

## TRUTH TABLE

INPUTS		FUNCTION		OUTPUT
$\bar{G}$	DIR	A BUS	B BUS	Y <sub>n</sub>
L	L	OUTPUT	INPUT	A = B
L	H	INPUT	OUTPUT	B = A
H	X	Z	Z	Z

X : Don't Care  
Z : High Impedance

## IEC LOGIC SYMBOLS



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	-0.5 to +4.6	V
$V_I$	DC Input Voltage	-0.5 to +4.6	V
$V_O$	DC Output Voltage (OFF State)	-0.5 to +4.6	V
$V_O$	DC Output Voltage (High or Low State) (note 1)	-0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	- 50	mA
$I_{OK}$	DC Output Diode Current (note 2)	- 50	mA
$I_O$	DC Output Current	$\pm 50$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current per Supply Pin	$\pm 100$	mA
$P_D$	Power Dissipation (for TSSOP)	400	mW
$T_{stg}$	Storage Temperature	-65 to +150	$^{\circ}C$
$T_L$	Lead Temperature (10 sec - for TSSOP)	300	$^{\circ}C$

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

1)  $I_O$  absolute maximum rating must be observed

2)  $V_O < GND$

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	1.8 to 3.6	V
$V_I$	Input Voltage	-0.3 to 3.6	V
$V_O$	Output Voltage (OFF State)	0 to 3.6	V
$V_O$	Output Voltage (High or Low State)	0 to $V_{CC}$	V
$I_{OH}, I_{OL}$	High or Low Level Output Current ( $V_{CC} = 3.0$ to $3.6V$ )	$\pm 24$	mA
$I_{OH}, I_{OL}$	High or Low Level Output Current ( $V_{CC} = 2.3$ to $2.7V$ )	$\pm 18$	mA
$I_{OH}, I_{OL}$	High or Low Level Output Current ( $V_{CC} = 1.8V$ )	$\pm 6$	mA
$T_{op}$	Operating Temperature	-55 to 125	$^{\circ}C$
dt/dv	Input Rise and Fall Time (note 1)	0 to 10	ns/V

1)  $V_{IN}$  from 0.8V to 2V at  $V_{CC} = 3.0V$

DC SPECIFICATIONS (2.7V < V<sub>CC</sub> ≤ 3.6V unless otherwise specified)

Symbol	Parameter	Test Condition		Value				Unit
		V <sub>CC</sub> (V)		-40 to 85 °C		-55 to 125 °C		
				Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	2.7 to 3.6		2.0		2.0		V
V <sub>IL</sub>	Low Level Input Voltage					0.8		
V <sub>OH</sub>	High Level Output Voltage	2.7 to 3.6	I <sub>O</sub> =-100 μA	V <sub>CC</sub> -0.2		V <sub>CC</sub> -0.2		V
		2.7	I <sub>O</sub> =-12 mA	2.2		2.2		
		3.0	I <sub>O</sub> =-18 mA	2.4		2.4		
			I <sub>O</sub> =-24 mA	2.2		2.2		
V <sub>OL</sub>	Low Level Output Voltage	2.7 to 3.6	I <sub>O</sub> =100 μA		0.2		0.2	V
		2.7	I <sub>O</sub> =12 mA		0.4		0.4	
		3.0	I <sub>O</sub> =18 mA		0.4		0.4	
			I <sub>O</sub> =24 mA		0.55		0.55	
I <sub>I</sub>	Input Leakage Current	2.7 to 3.6	V <sub>I</sub> = 0 to 3.6V		± 5		± 5	μA
I <sub>off</sub>	Power Off Leakage Current	0	V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6V		10		10	μA
I <sub>OZ</sub>	High Impedance Output Leakage Current	2.7 to 3.6	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = 0 to 3.6V		± 10		± 10	μA
I <sub>CC</sub>	Quiescent Supply Current	2.7 to 3.6	V <sub>I</sub> = V <sub>CC</sub> or GND		20		20	μA
			V <sub>I</sub> or V <sub>O</sub> = V <sub>CC</sub> to 3.6V		± 20		± 20	
ΔI <sub>CC</sub>	I <sub>CC</sub> incr. per Input	2.7 to 3.6	V <sub>IH</sub> = V <sub>CC</sub> - 0.6V		750		750	μA

## 74VCX16245

### DC SPECIFICATIONS ( $2.3V < V_{CC} \leq 2.7V$ unless otherwise specified)

Symbol	Parameter	Test Condition		Value				Unit
		V <sub>CC</sub> (V)		-40 to 85 °C		-55 to 125 °C		
				Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	2.3 to 2.7		1.6		1.6		V
V <sub>IL</sub>	Low Level Input Voltage				0.7		0.7	
V <sub>OH</sub>	High Level Output Voltage	2.3 to 2.7	I <sub>O</sub> =-100 μA	V <sub>CC</sub> -0.2		V <sub>CC</sub> -0.2		V
				I <sub>O</sub> =-6 mA	2.0		2.0	
		2.3	I <sub>O</sub> =-12 mA	1.8		1.8		
			I <sub>O</sub> =-18 mA	1.7		1.7		
V <sub>OL</sub>	Low Level Output Voltage	2.3 to 2.7	I <sub>O</sub> =100 μA		0.2		0.2	V
				I <sub>O</sub> =12 mA		0.4		
		2.3	I <sub>O</sub> =18 mA		0.6		0.6	
I <sub>I</sub>	Input Leakage Current	2.3 to 2.7	V <sub>I</sub> = 0 to 3.6V		± 5		± 5	μA
I <sub>off</sub>	Power Off Leakage Current	0	V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6V		10		10	μA
I <sub>OZ</sub>	High Impedance Output Leakage Current	2.3 to 2.7	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = 0 to 3.6V		± 10		± 10	μA
I <sub>CC</sub>	Quiescent Supply Current	2.3 to 2.7	V <sub>I</sub> = V <sub>CC</sub> or GND		20		20	μA
			V <sub>I</sub> or V <sub>O</sub> = V <sub>CC</sub> to 3.6V		± 20		± 20	

### DC SPECIFICATIONS ( $1.8V \leq V_{CC} \leq 2.3V$ unless otherwise specified)

Symbol	Parameter	Test Condition		Value				Unit
		V <sub>CC</sub> (V)		-40 to 85 °C		-55 to 125 °C		
				Min.	Max.	Min.	Max.	
V <sub>IH</sub>	High Level Input Voltage	1.8 to 2.3		0.7 V <sub>CC</sub>		0.7 V <sub>CC</sub>		V
V <sub>IL</sub>	Low Level Input Voltage				0.2 V <sub>CC</sub>		0.2 V <sub>CC</sub>	V
V <sub>OH</sub>	High Level Output Voltage	1.8	I <sub>O</sub> =-100 μA	V <sub>CC</sub> -0.2		V <sub>CC</sub> -0.2		V
				I <sub>O</sub> =-6 mA	1.4		1.4	
V <sub>OL</sub>	Low Level Output Voltage	1.8	I <sub>O</sub> =100 μA		0.2		0.2	V
				I <sub>O</sub> =6 mA		0.3		
I <sub>I</sub>	Input Leakage Current	1.8	V <sub>I</sub> = 0 to 3.6V		± 5		± 5	μA
I <sub>off</sub>	Power Off Leakage Current	0	V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6V		10		10	μA
I <sub>OZ</sub>	High Impedance Output Leakage Current	1.8	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>O</sub> = 0 to 3.6V		± 10		± 10	μA
I <sub>CC</sub>	Quiescent Supply Current	1.8	V <sub>I</sub> = V <sub>CC</sub> or GND		20		20	μA
			V <sub>I</sub> or V <sub>O</sub> = V <sub>CC</sub> to 3.6V		± 20		± 20	

**DYNAMIC SWITCHING CHARACTERISTICS** ( $T_a = 25^\circ\text{C}$ , Input  $t_r = t_f = 2.0\text{ns}$ ,  $C_L = 30\text{pF}$ ,  $R_L = 500\Omega$ )

Symbol	Parameter	Test Condition		Value			Unit
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			
				Min.	Typ.	Max.	
$V_{OLP}$	Dynamic Low Voltage Quiet Output (note 1, 3)	1.8	$V_{IL} = 0\text{V}$ $V_{IH} = V_{CC}$		0.25		V
		2.5			0.6		
		3.3			0.8		
$V_{OLV}$	Dynamic Low Voltage Quiet Output (note 1, 3)	1.8	$V_{IL} = 0\text{V}$ $V_{IH} = V_{CC}$		-0.25		V
		2.5			-0.6		
		3.3			-0.8		
$V_{OHV}$	Dynamic High Voltage Quiet Output (note 2, 3)	1.8	$V_{IL} = 0\text{V}$ $V_{IH} = V_{CC}$		1.5		V
		2.5			1.9		
		3.3			2.2		

1) Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.

2) Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the HIGH state.

3) Parameters guaranteed by design.

**AC ELECTRICAL CHARACTERISTICS** ( $C_L = 30\text{pF}$ ,  $R_L = 500\Omega$ , Input  $t_r = t_f = 2.0\text{ns}$ )

Symbol	Parameter	Test Condition		Value				Unit
		$V_{CC}$ (V)		$-40$ to $85^\circ\text{C}$		$-55$ to $125^\circ\text{C}$		
				Min.	Max.	Min.	Max.	
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time	1.8		1.5	5.7	1.5	7.0	ns
		2.3 to 2.7		1.0	3.2	1.0	4.0	
		3.0 to 3.6		0.8	2.5	0.8	3.4	
$t_{PZL}$ $t_{PZH}$	Output Enable Time	1.8		1.5	7.5	1.5	9.0	ns
		2.3 to 2.7		1.0	4.9	1.0	6.0	
		3.0 to 3.6		0.8	3.8	0.8	4.7	
$t_{PLZ}$ $t_{PHZ}$	Output Disable Time	1.8		1.5	5.5	1.5	6.8	ns
		2.3 to 2.7		1.0	4.2	1.0	5.0	
		3.0 to 3.6		0.8	3.7	0.8	4.6	
$t_{OSLH}$ $t_{OSHL}$	Output To Output Skew Time (note 1, 2)	1.8			0.5		0.5	ns
		2.3 to 2.7			0.5		0.5	
		3.0 to 3.6			0.5		0.5	

1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW ( $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$ ,  $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ )

2) Parameter guaranteed by design

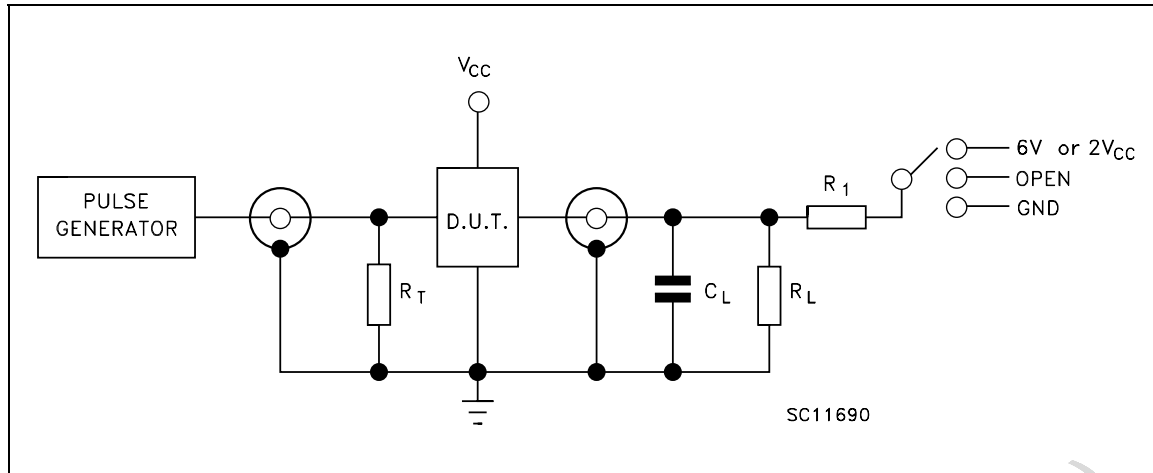
**CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Test Condition		Value			Unit
		$V_{CC}$ (V)		$T_A = 25^\circ\text{C}$			
				Min.	Typ.	Max.	
$C_{IN}$	Input Capacitance	1.8, 2.5 or 3.3	$V_{IN} = 0$ or $V_{CC}$		4		pF
$C_{OUT}$	Output Capacitance	1.8, 2.5 or 3.3	$V_{IN} = 0$ or $V_{CC}$		8		pF
$C_{PD}$	Power Dissipation Capacitance (note 1)	1.8, 2.5 or 3.3	$f_{IN} = 10\text{MHz}$ $V_{IN} = 0$ or $V_{CC}$		28		pF

1)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/16$  (per circuit)



## TEST CIRCUIT



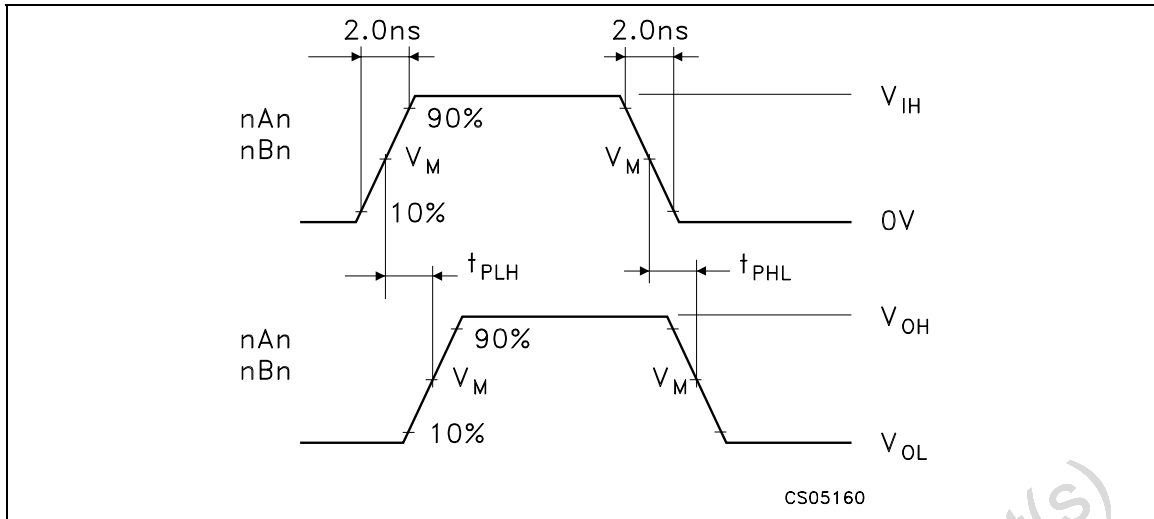
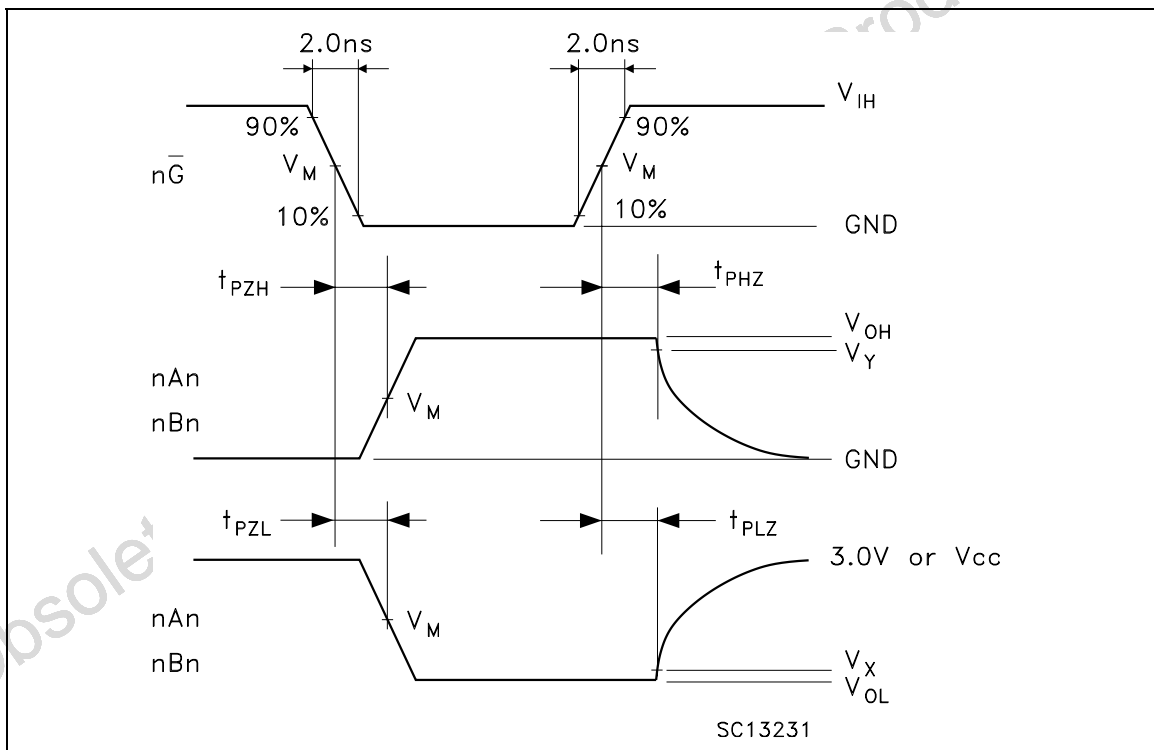
TEST	SWITCH
$t_{PLH}$ , $t_{PHL}$	Open
$t_{PZL}$ , $t_{PLZ}$ ( $V_{CC} = 3.0$ to $3.6V$ )	6V
$t_{PZL}$ , $t_{PLZ}$ ( $V_{CC} = 2.3$ to $2.7V$ or $1.8V$ )	$2V_{CC}$
$t_{PZH}$ , $t_{PHZ}$	GND

$C_L = 30$  pF or equivalent (includes jig and probe capacitance)  
 $R_L = R_1 = 500\Omega$  or equivalent  
 $R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

## WAVEFORM SYMBOL VALUES

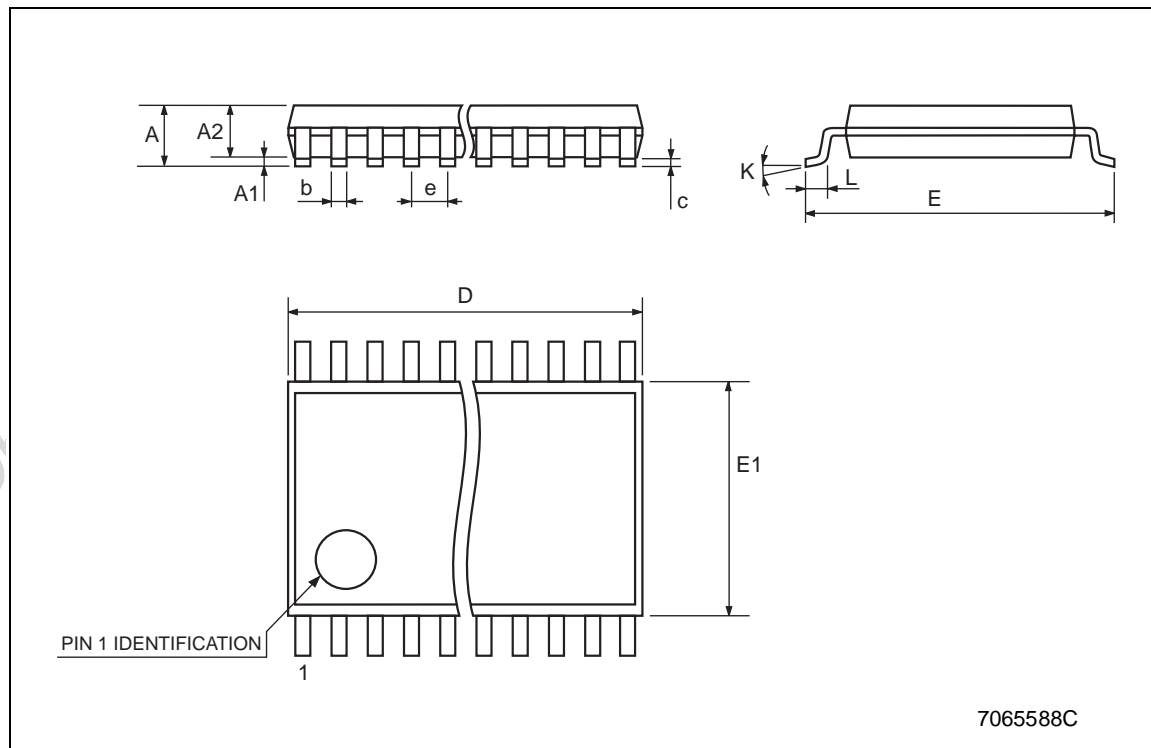
Symbol	$V_{CC}$		
	3.0 to 3.6V	2.3 to 2.7V	1.8V
$V_{IH}$	2.7V	$V_{CC}$	$V_{CC}$
$V_M$	1.5V	$V_{CC}/2$	$V_{CC}/2$
$V_X$	$V_{OL} + 0.3V$	$V_{OL} + 0.15V$	$V_{OL} + 0.15V$
$V_Y$	$V_{OH} - 0.3V$	$V_{OH} - 0.15V$	$V_{OH} - 0.15V$



**WAVEFORM 1: PROPAGATION DELAYS** (f=1MHz; 50% duty cycle)**WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIME** (f=1MHz; 50% duty cycle)

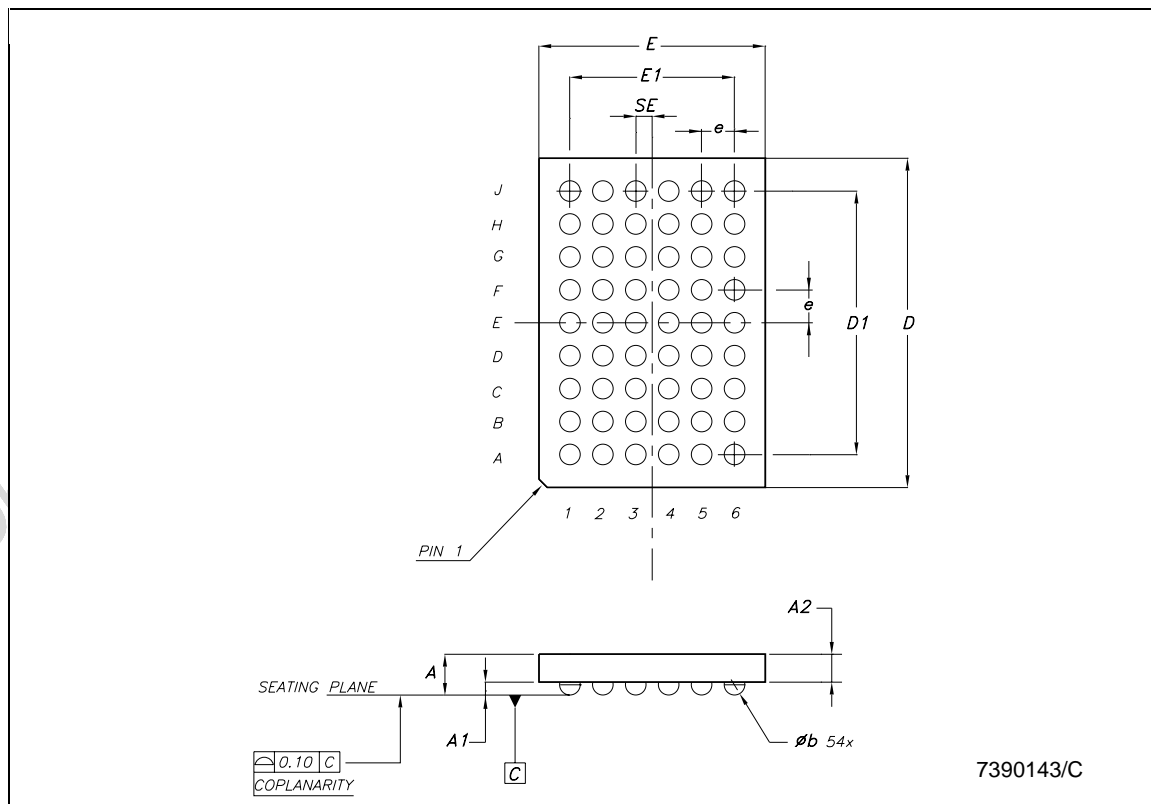
## TSSOP48 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2		0.9			0.035	
b	0.17		0.27	0.0067		0.011
c	0.09		0.20	0.0035		0.0079
D	12.4		12.6	0.488		0.496
E		8.1 BSC			0.318 BSC	
E1	6.0		6.2	0.236		0.244
e		0.5 BSC			0.0197 BSC	
K	0°		8°	0°		8°
L	0.50		0.75	0.020		0.030



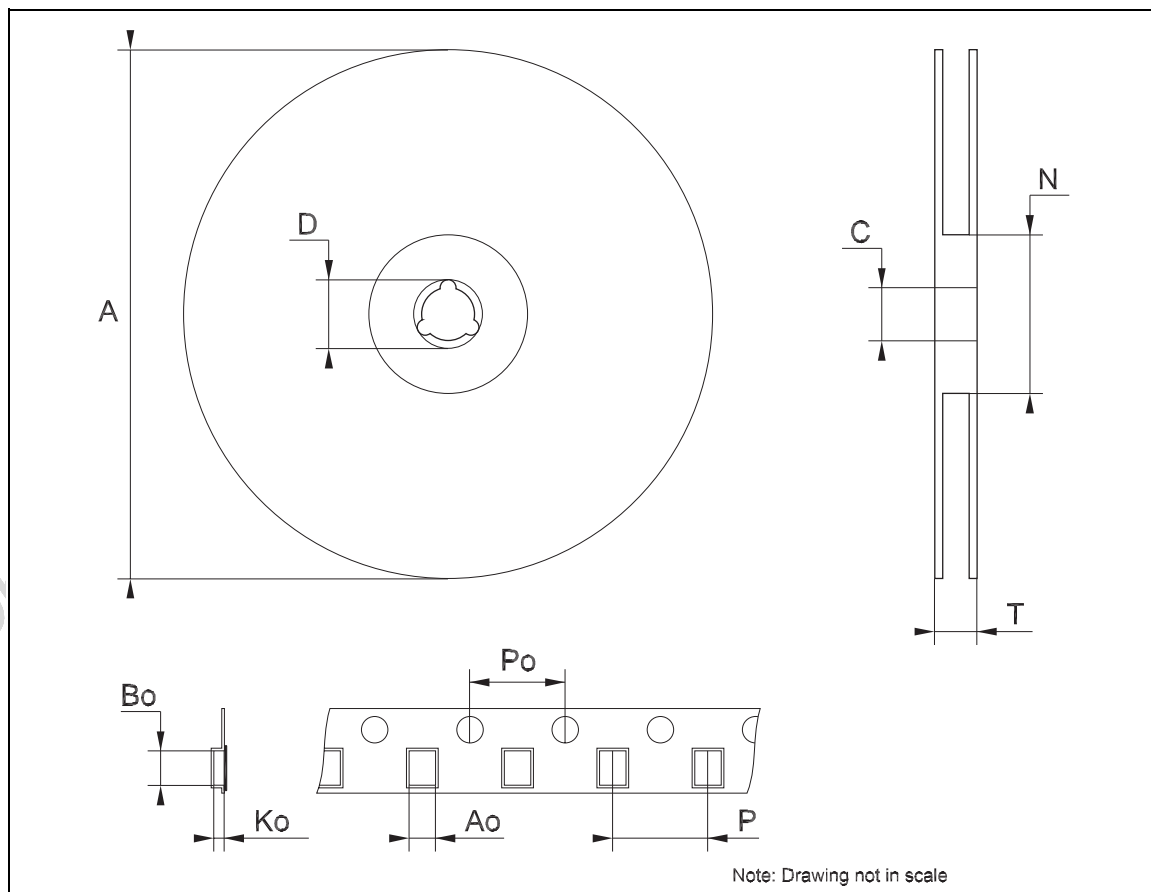
## TFBGA54 MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			47.2
A1	0.25			9.8		
A2	0.78		0.86	30.7		33.8
B	0.35	0.4	0.45	13.7	15.7	17.7
D	7.9		8.1	311.0		318.9
D1		6.4			252.0	
E	5.4	5.5	5.6	212.6	216.5	220.5
E1		4			157.5	
e		0.8			31.5	
SE		0.4			15.7	



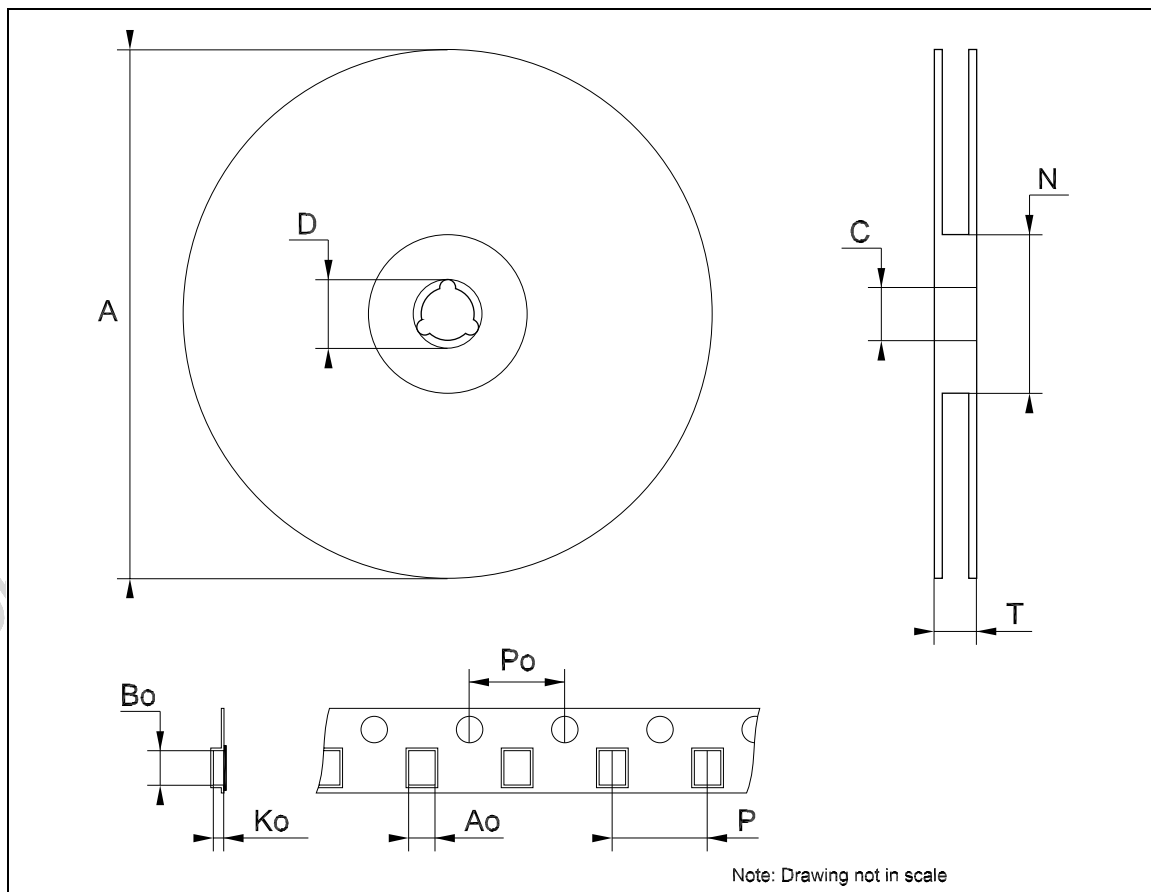
## Tape &amp; Reel TSSOP48 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			30.4			1.197
Ao	8.7		8.9	0.343		0.350
Bo	13.1		13.3	0.516		0.524
Ko	1.5		1.7	0.059		0.067
Po	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476



### Tape & Reel TFBGA54 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			22.4			0.882
Ao		6.1			0.240	
Bo		8.6			0.339	
Ko		1.8			0.071	
Po	3.9		4.1	0.153		0.161
P	7.9		8.1	0.311		0.319



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics  
All other names are the property of their respective owners

© 2003 STMicroelectronics - All Rights Reserved  
STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.  
<http://www.st.com>